# **David Maeso,** Andrés Castellanos-Gomez, Nicolás Agrait and Gabino Rubio-Bollinger

Departamento de Física de la Materia Condensada, Universidad Autónoma de Madrid, 28049 Madrid, Spain

## Email: david.maeso@uam.es

Semiconductor two-dimensional (2D) materials are an emerging class of materials with a wide range of electrical and optical properties. Molybdenum disulfide ( $MoS_2$ ) is one of the most studied 2D materials because of its unique quantum confinement.

Vertical photodevices are prepared using a physical vapor deposition method to fabricate the gold (Au) substrate.  $MoS_2$  nanosheets are produced by mechanical exfoliation using a polydimethylsiloxane (PDMS) viscoelastic stamps and are transferred onto the Au substrate by an all-dry deterministic method<sup>[1]</sup>. The photodevice is completed by evaporating 8  $\mu$ m Au disks over the MoS<sub>2</sub> nanosheets as seen in Figure 1. The photodevices are illuminated using a white supercontinuum laser source and a single grating Czerny-Turner monochromator is used to select the excitation wavelengths.

*I-V* characteristics are measured using an asynchronous set-up and allow us to determine either dark *IV* or illuminated *IV*. Our metal-semiconductor-metal (MSM) photodevice can be modeled as two metal-semiconductor diodes connected back to back<sup>[2]</sup>. Experimental *IV* characteristics are fitted to the model demonstrating a very good agreement. Schottky barriers and ideality factors are extracted from the fitted data and are consistent with the literature<sup>[3]</sup>.

Figures of merit of spectral photoresponsivity and spectral external quantum efficiency at different voltages are extracted from the *IV* characteristics as seen in Figure 2. Two peaks at 1.86 and 2.05 eV are observed and are related to the bound excitons A and B.

High photoresponsivity and external quantum efficiency are obtained in vertical photodevices opening a new path to explore this vertical photodevices.

## High photoresponsivity in vertically stacked MoS<sub>2</sub> photodevices

## References

- [1] Castellanos-Gomez, A. et al. 2D Materials 1, 011002 (2014).
- [2] Bao, H. et al. Small 4, 1125-1129 (2008).
- [3] Quereda et al. 2D Materials 4, 021006 (2017).

### Figures



Figure 1: Schematic illustrating the experimental set-up.



Figure 2: Photoresponsivity and External Quantum Efficiency of the vertical  $MoS_2$  photodevices.